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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants	:	Fazan et al.) Group Art Unit 2823
Appl. No.	:	09/037,945) I hereby certify that this correspondence and all marked attachments are being deposited with
Filed	:	March 10, 1998	the United States Postal Service as first-class mail in an envelope addressed to: Assistant Commissioner for Patents, Washington, D.C.
For	:	STREAMLINED FIELD ISOLATION PROCESS) 20231, on)
Examiner	:	George Fourson	James B. Bear, Reg. No. 25;221

AMENDMENT AFTER FINAL

Assistant Commissioner for Patents Washington, D.C. 20231

Dear Sir:

This is a response to the Office Action mailed on January 12, 2000, in which all of the pending claims were finally rejected. This Amendment After Final amends all of the pending claims, but is not believed to raise new issues. Rather, it is believed that the amendments clarify the claimed process in a manner which avoids the prior art without altering the principal focus of the claims. For this reason, and because the amendments clarify the patentable features of the method for any possible appeal, entry of these amendments is earnestly solicited.

In the Claims:

- 1. (Thrice Amended) A process of forming an integrated circuit, comprising: growing a silicon dioxide field isolation region on a semiconductor wafer without forming silicon nitride inclusions in said field isolation region exclusively by means of a hydrogen-free oxidant at a pressure less than about 30 atm; and forming a gate oxide without a prior sacrificial oxidation.
- 8. (Thrice Amended) A field isolation region among integrated circuit devices on a semiconductor substrate formed by a process comprising: